

25A SILICON POWER RECTIFIER DIODE

Description

The BYP53/54 are plastic sealed 25A- diodes, which are available in different reverse voltage classes up to 800V.

The diodes can be delivered with limited forward voltage and reverse current differences for parallel connecting in rectifier stacks and back-off-diodes

Features

- Forward current 25A
- Reverse voltage 75V 800V
- Hermetic press-fit package
- Available in different modifications of the package
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

Applications

- Power supplies
- · Rectifier diode in car generators
- · Rectifier bridges/stacks
- Back-off-diodes

Pinout details

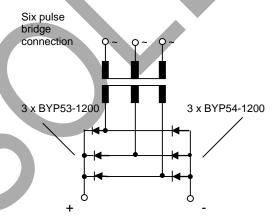


BYP53:1 - cathode 2 - anode

BYP54:1 - anode

2 - cathode

Typical application circuit



Ordering information

Device	Quantity per box	Options
BYP53-75;; BYP53-800		The package quantities for the different package
BYP54-75;; BYP54-800	400	modifications are included in "PressFitPackageModifications.pdf"

Device marking

Devices are identified by type. Colour of marking: BYP53- black, BYP54 - red

422		date code 422 = 2004 week 22
/ ZETEX `	\	
♦ BYP53)	diode type
400/.		repetitive peak reverse voltage V _{RRM} (in V) 400



Absolute maximum ratings (at T_{amb} = 25°C unless otherwise stated)

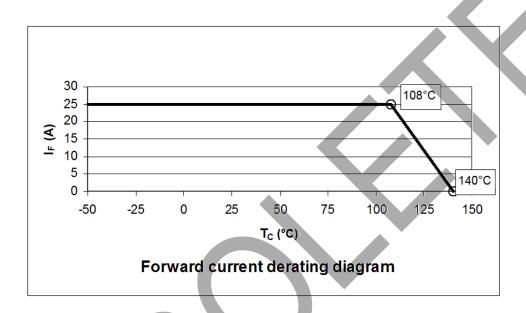
Parameter			Symbol		Unit	Test condition
	BYP53-75	BYP54-75		75	V	
	BYP53-100	BYP54-100		100		
	BYP53-150	BYP54-150		150		
	BYP53-200	BYP54-200		200		
Repetitive peak	BYP53-300	BYP54-300		300		Tc=140°C
reverse voltage	BYP53-400	BYP54-400	V_{RRM}	400		Tc= 140 C
	BYP53-500	BYP54-500		500		
	BYP53-600	BYP54-600		600		
	BYP53-700	BYP54-700		700		
	BYP53-800	BYP54-800		800		
Forward cu	rrent, arithmetic	value	I _{FAV}	25	A	
Surge forward current			IFSM	425 350	A	half-sine wave, ≤ 10 ms T _J = 175°C half-sine wave, ≤ 10 ms
Maximum rated value			∫i²dt	900	A²s	half-sine wave, \leq 10 ms $T_J = 175^{\circ}\text{C half-sine}$ wave, \leq 10 ms
Repetitive peak forward current			I _{FRM} =π*I _{FAV}	79	Α	f = >15 Hz
Effective forward current			I _{FRMS}	45	Α	
Junction temperature			T _{Jmax}	175	°C	
Storage temperature range			T _{stg}	- 50 to + 140	°C	



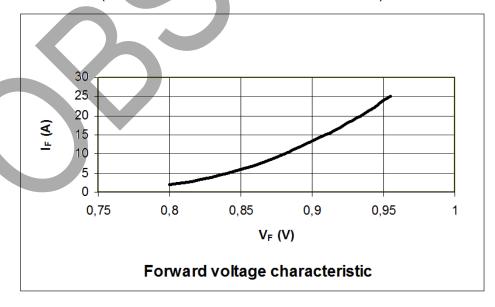
Thermal resistance

Parameter	arameter Symbol		Unit		
Junction to case	Rejc	1.2	°C/W		

Thermal characteristics



Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)





Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)

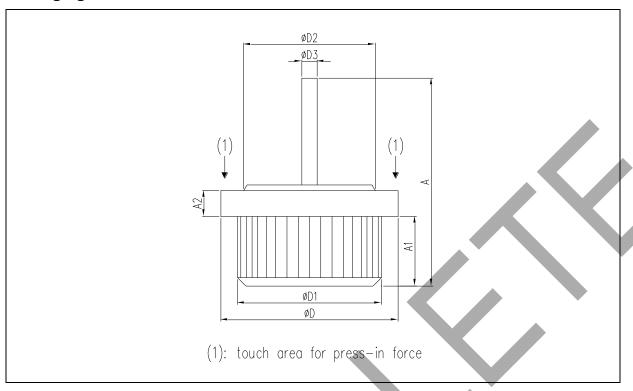
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Forward voltage	BYP53-75800 BYP54-75800	VF	-	0.95	1.1	V	I _F = 25 A, measuring time 10ms (half-sine wave)
Forward voltage (information values)	BYP53-75800 BYP54-75800	V _F	-	1	1.2	V	I _F = 35 A,
Reverse current	BYP53-75150 BYP54-75150		-	-	3	A	T _J = 140°C, at
	BYP53-200800 BYP54-200800	- I _{RRM}	-	-	1.5	mA	V _{RRM}
	BYP53-75400 BYP54-75400		-	-	0.25		
	BYP53-500800 BYP54-500800	- I _{RRM}	-	-	0.1	mA	at V _{RRM}
Threshold voltage (information value)		V _(FO)		0.66	-	V	T _J = 175°C
Slope resistance (information value)		r _F	-	5.75	X	mΩ	T _J = 175°C

Options: Electrical characteristics for parallel connecting (at $T_{amb} = 25$ °C unless otherwise stated)

Option	Parameter	Symbol	Min.	Тур.	Max.	Unit	Test contitions
1	Forward voltage difference in one category of forward voltage	ΔV _F	·		0.05	V	I _F = 25 A, measuring time 10ms (half-sine wave)
2	Reverse current in one category of forward voltage (only for BYP53-300800 and BYP54-300800)	İR		-	0.01	mA	at V _{RRM}



Packaging details



Package dimensions

Dimensions in millimeters are control dimensions, dimensions in inches are approximate

DIM		Millimeters		Inches			
	MIN	TYP	MAX	MIN	TYP	MAX	
Α	18,00	18,50	19,00	0,709	0,728	0,748	
A1	5,90	6,10	6,30	0,232	0,240	0,248	
A2	2,10	2,30	2,50	0,083	0,091	0,098	
D	15,50	15,70	15,90	0,610	0,618	0,626	
D1	12,72	12,77	12,82	0,501	0,503	0,505	
D2	11,50	11,70	11,90	0,453	0,461	0,469	
D3	1,33	1,36	1,39	0,052	0,054	0,055	



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